## onsemi

## **Single 2-Input AND Gate**

## MC74VHC1G08, MC74VHC1GT08

The MC74VHC1G08 / MC74VHC1GT08 is a single 2 input AND gate in tiny footprint packages. The MC74VHC1G08 has CMOS-level input thresholds while the MC74VHC1GT08 has TTL-level input thresholds.

The input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage. This allows the device to be used to interface 5 V circuits to 3 V circuits. Some output structures also provide protection when  $V_{CC} = 0$  V and when the output voltage exceeds  $V_{CC}$ . These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

### Features

- Designed for 2.0 V to 5.5 V  $V_{CC}$  Operation
- 3.5 ns t<sub>PD</sub> at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- IOFF Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- -Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

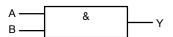
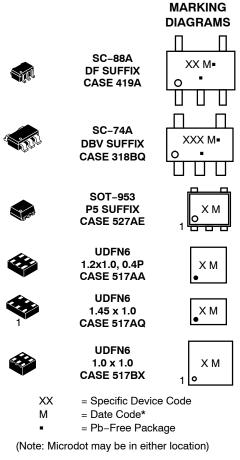


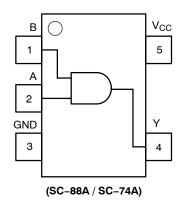
Figure 1. Logic Symbol

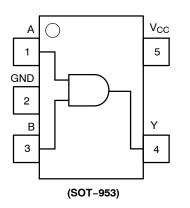


\*Date Code orientation and/or position may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 7 of this data sheet.





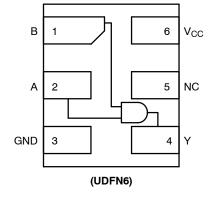


Figure 2. Pinout (Top View)

## **PIN ASSIGNMENT**

(SC-88A / SC-74A)

Pin	Function
1	В
2	A
3	GND
4	Y
5	V <sub>CC</sub>

PIN ASSIGNMEN	T (SOT-953)

Pin	Function
1	А
2	GND
3	В
4	Y
5	V <sub>CC</sub>

## **PIN ASSIGNMENT (UDFN)**

Pin	Function
1	В
2	A
3	GND
4	Y
5	NC
6	V <sub>CC</sub>

## FUNCTION TABLE

Inp	Output	
Α	В	Y
L	L	L
L	Н	L
н	L	L
Н	Н	Н

### **MAXIMUM RATINGS**

Symbol	Characteristics	Value	Unit			
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V		
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V		
V <sub>OUT</sub>	Tri	e (High or Low State) –State Mode (Note 1) wn Mode (V <sub>CC</sub> = 0 V)	$\begin{array}{c} -0.5 \text{ to } V_{CC} + 0.5 \\ -0.5 \text{ to } +6.5 \\ -0.5 \text{ to } +6.5 \end{array}$	V		
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA		
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND				
I <sub>OUT</sub>	DC Output Source/Sink Current		±25	mA		
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pin	±50	mA			
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C		
ΤL	Lead Temperature, 1 mm from Case for 10 secs		260	°C		
TJ	Junction Temperature Under Bias		+150	°C		
$\theta_{JA}$	Thermal Resistance (Note 2)	SC-88A SC-74A SOT-553 SOT-953 UDFN6	377 320 324 254 154	°C/W		
PD	Power Dissipation in Still Air	SC-88A SC-74A SOT-553 SOT-953 UDFN6	332 390 386 491 812	mW		
MSL	Moisture Sensitivity		Level 1	-		
F <sub>R</sub>	Flammability Rating O	xygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-		
$V_{\text{ESD}}$	ESD Withstand Voltage (Note 3) C	Human Body Model harged Device Model	2000 1000	V		
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality

Shresses exceeding mose listed in the Maximum Hatings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
 Applicable to devices with outputs that may be tri-stated.
 Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
 Tested to EIA/IESD7 Class II.

4. Tested to EIA/JESD78 Class II.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Characteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	V
T <sub>A</sub>	Operating Temperature Range	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0 0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS (MC74VHC1G08)

		Test	Vcc	٦	Γ <sub>A</sub> = 25°	C	-40°C ≤ -	<b>F<sub>A</sub> ≤ 85°C</b>	–55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
VIH	High-Level Input		2.0	1.5	-	-	1.5	-	1.5	-	V
	Voltage		3.0	2.1	-	-	2.1	-	2.1	-	
			4.5	3.15	-	-	3.15	-	3.15	-	
			5.5	3.85	-	-	3.85	-	3.85	-	
VIL	Low-Level Input		2.0	-	-	0.5	-	0.5	-	0.5	V
	Voltage		3.0	-	-	0.9	-	0.9	-	0.9	
			4.5	-	-	1.35	-	1.35	-	1.35	
			5.5	-	-	1.65	-	1.65	-	1.65	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -4 \ m\text{A} \\ I_{OH} = -8 \ m\text{A} \end{array}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 –	- - - -	1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 50 \ \mu A \\ I_{OL} = 4 \ m A \\ I_{OL} = 8 \ m A \end{array} $	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	$V_{IN}$ = 5.5 V or $V_{OUT}$ = 5.5 V	0.0	-	-	1.0	-	10	-	10	μΑ
ICC	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	-	40	μΑ

DC ELECTRICAL	CHARACTERISTICS	(MC74VHC1GT08)
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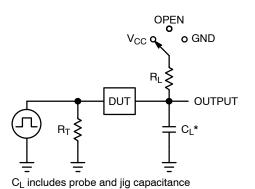
		Test	Vcc	T <sub>A</sub> = 25°C			-40°C ≤ -	<b>T<sub>A</sub> ≤ 85°C</b>	<b>-55°C</b> ≤ 1	Γ <sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	v cc (V)	Min	Тур	Max	Min	Max	Min	Max	Unit
$V_{\text{IH}}$	High-Level Input		2.0	1.0	-	-	1.0	-	1.0	-	V
	Voltage		3.0	1.4	-	-	1.4	-	1.4	-	1
			4.5	2.0	-	-	2.0	-	2.0	-	
			5.5	2.0	-	-	2.0	-	2.0	-	1
$V_{IL}$	Low-Level Input		2.0	-	-	0.28	-	0.28	-	0.28	V
	Voltage		3.0	-	1	0.45	1	0.45	-	0.45	
			4.5	-	I	0.8	-	0.8	-	0.8	
			5.5	-	-	0.8	-	0.8	-	0.8	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -4 \ m\text{A} \\ I_{OH} = -8 \ m\text{A} \end{array}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 –	- - - -	1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 50 \ \mu A \\ I_{OL} = 50 \ \mu A \\ I_{OL} = 50 \ \mu A \\ I_{OL} = 4 \ m A \\ I_{OL} = 8 \ m A \end{array} $	2.0 3.0 4.5 3.0 4.5	- - -	0.0 0.0 0.0 - -	0.1 0.1 0.36 0.36	- - -	0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	_	-	1.0	-	10	-	10	μA
ICC	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	-	40	μA
I <sub>CCT</sub>	Increase in Quies- cent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5	-	-	1.35	-	1.5	_	1.65	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### AC ELECTRICAL CHARACTERISTICS

				Ţ	A = 25°	C	<b>-40°C</b> ≤ 1	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	4.1	8.8	-	10.5	-	12.5	ns
tPHL	A to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		-	5.9	12.3	-	14.0	-	16.5	
		C <sub>L</sub> = 15 pF	4.5 to 5.5	-	3.5	5.9	-	7.0	-	9.0	
		C <sub>L</sub> = 50 pF		-	4.2	7.9	-	9.0	-	11.0	
C <sub>IN</sub>	Input Capacitance			-	4.0	10	-	10	-	10	pF
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State		-	6.0	-	_	_	-	_	pF
Symbol	Parameter							Typical (	@ 25°C, V <sub>C</sub>	c = 5.0 V	Unit
C <sub>PD</sub>	Power Dissipation Ca	pacitance (Not	e 5)						8.0		pF

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

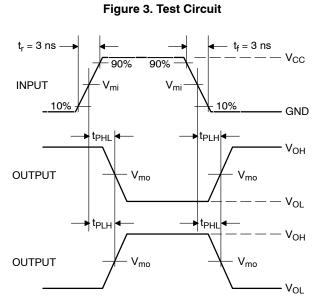


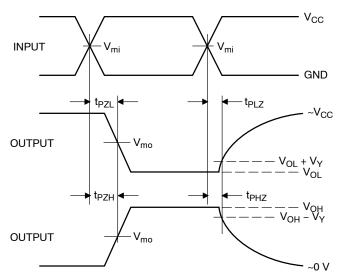
 $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

f = 1 MHz

Test	Switch Position	С <sub>L</sub> , pF	$R_{L}, \Omega$
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics Table	Х
t <sub>PLZ</sub> / t <sub>PZL</sub>	V <sub>CC</sub>		1 k
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND		1 k

X = Don't Care





### Figure 4. Switching Waveforms

		V <sub>m</sub> o		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> , t <sub>PZH</sub> , t <sub>PHZ</sub>	V <sub>Y</sub> , V
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

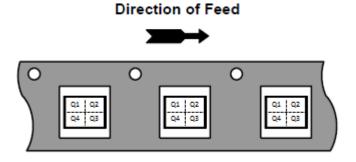
### **ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC1G08DFT1G	SC-88A	V2	Q2	3000 / Tape & Reel
MC74VHC1G08DFT2G	SC-88A	V2	Q4	3000 / Tape & Reel
MC74VHC1G08DFT1G-Q*	SC-88A	V2	Q2	3000 / Tape & Reel
MC74VHC1G08DFT2G-Q*	SC-88A	V2	Q4	3000 / Tape & Reel
MC74VHC1GT08DFT1G	SC-88A	VT	Q2	3000 / Tape & Reel
MC74VHC1GT08DFT2G	SC-88A	VT	Q4	3000 / Tape & Reel
MC74VHC1GT08DFT1G-Q*	SC-88A	VT	Q2	3000 / Tape & Reel
MC74VHC1GT08DFT2G-Q*	SC-88A	VT	Q4	3000 / Tape & Reel
MC74VHC1G08DBVT1G	SC-74A	V2	Q4	3000 / Tape & Reel
MC74VHC1G08DBVT1G-Q*	SC-74A	V2	Q4	3000 / Tape & Reel
MC74VHC1GT08DBVT1G	SC-74A	VT	Q4	3000 / Tape & Reel
MC74VHC1GT08DBVT1G-Q*	SC-74A	VT	Q4	3000 / Tape & Reel
MC74VHC1G08P5T5G	SOT-953	E	Q2	8000 / Tape & Reel
MC74VHC1GT08P5T5G	SOT-953	Р	Q2	8000 / Tape & Reel
MC74VHC1G08MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	K (Rotated 180° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT08MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	4 (Rotated 270° CW)	Q4	3000 / Tape & Reel
MC74VHC1G08MU2TCG	UDFN6, 1.2 x 1.0, 0.4P	2	Q4	3000 / Tape & Reel
MC74VHC1G08MU3TCG	UDFN6, 1.0 x 1.0, 0.35	D (Rotated 270° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT08MU3TCG	UDFN6, 1.0 x 1.0, 0.35	К	Q4	3000 / Tape & Reel

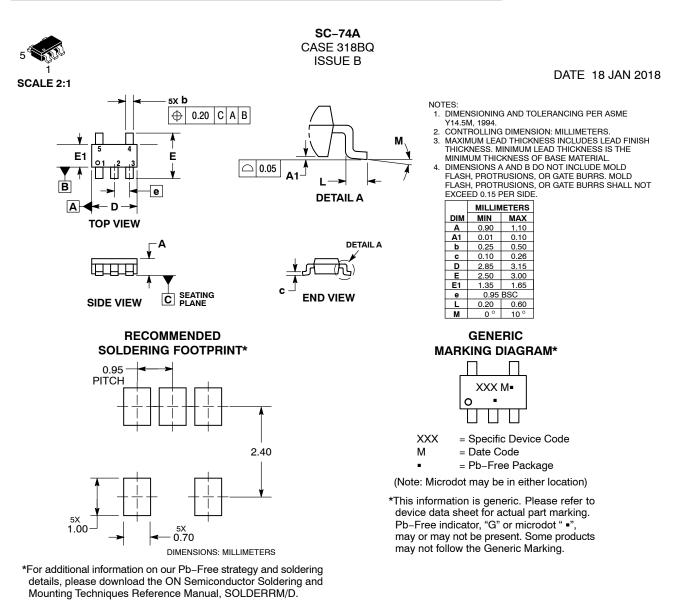
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging

Specifications Brochure, BRD8011/D. \*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

## **PIN 1 ORIENTATION IN TAPE AND REEL**







DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SC-74A PAGE 1 OI				
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#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

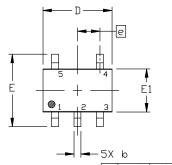
NDTES: 1. DIM

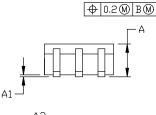
2.

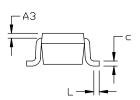
З.

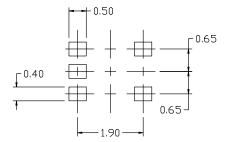
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DATE 11 APR 2023









#### RECOMMENDED MOUNTING FOOTPRINT

 For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

лтм	MI	MILLIMETERS			
DIM	MIN.	NDM.	MAX.		
Α	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
C	0.10		0.25		
D	1.80	2.00	2.20		
E	2.00	2.10	2.20		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSDLETE, NEW STANDARD 419A-02

## **GENERIC MARKING**





\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

(Note: Microdot may be in either location)

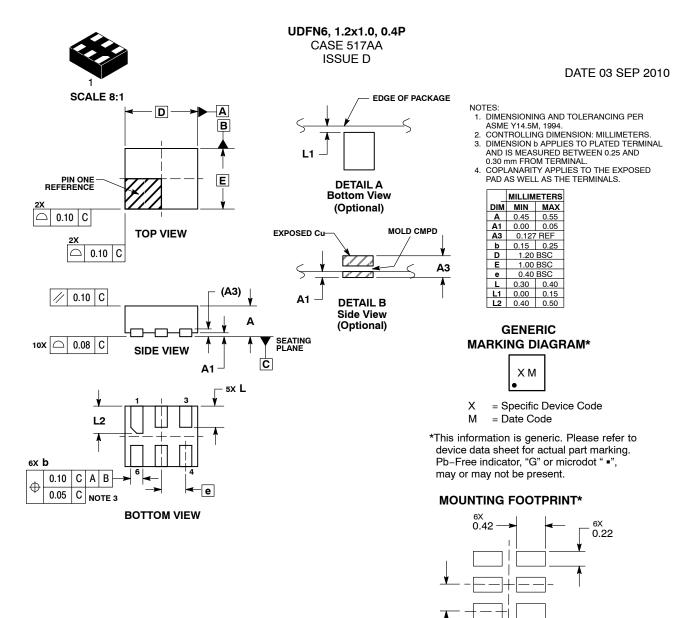
DOCUMENT NUMBER:      98ASB42984B      Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.        DESCRIPTION:      SC-88A (SC-70-5/SOT-353)      PAGE 1 OF 1	PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	style callout. If style t out in the datasheet datasheet pinout or p	refer to the device
DESCRIPTION: SC-88A (SC-70-5/SOT-353) PAGE 1 OF 1	DOCUMENT NUMBER:	98ASB42984B				
	DESCRIPTION:	SC-88A (SC-70-	5/SOT-353)			PAGE 1 OF 1

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XXX = Specific Device Code

M = Date Code = Pb-Free Package

# **ONSEM**<sup>1</sup>.



DIMENSIONS: MILLIMETERS

1.07

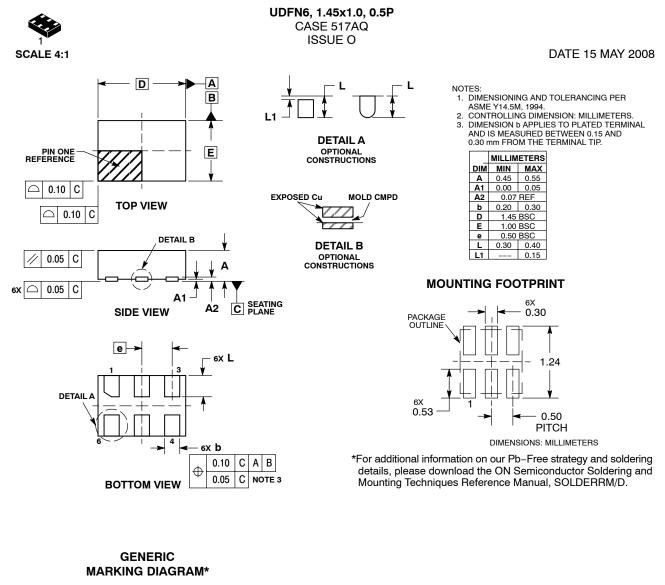
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

0.40

PITCH

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DESCRIPTION:	6 PIN UDFN, 1.2X1.0, 0.4P PAGE 1		PAGE 1 OF 1		
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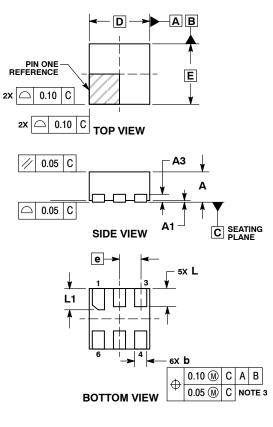
- X = Specific Device Code
- M = Date Code
- \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

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# DUSem



SCALE 4:1



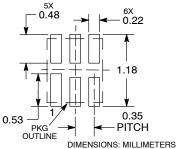
UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

#### DATE 18 MAY 2011

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN A DE ADD & OR MULTICAL TERMINAL TR
- AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FL					
	MILLIN	MILLIMETERS			
DIM	MIN MAX				
Α	0.45	0.55			
A1	0.00	0.05			
A3	0.13	REF			
b	0.12 0.22				
D	1.00 BSC				
E	1.00 BSC				
е	0.35 BSC				
L	0.25 0.35				
L1	0.30	0.40			

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### GENERIC **MARKING DIAGRAM\***



X = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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SCALE 4:1

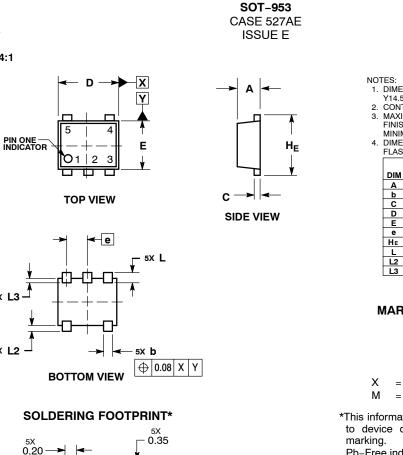
5X L3

5X L2

PACKAGE OUTLINE

0.35 PITCH





#### DATE 02 AUG 2011

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS						
DIM	MIN	MIN NOM MAX					
Α	0.34	0.37	0.40				
b	0.10	0.15	0.20				
С	0.07	0.12	0.17				
D	0.95	1.00	1.05				
E	0.75	0.80	0.85				
е	0.35 BSC						
ΗE	0.95	1.00	1.05				
L	0.175 REF						
L2	0.05	0.10	0.15				
L3			0.15				

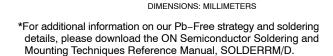
## GENERIC **MARKING DIAGRAM\***

= Specific Device Code

= Month Code

\*This information is generic. Please refer to device data sheet for actual part

Pb-Free indicator, "G" or microdot " .", may or may not be present.



L

1.20

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